



DXT13003DG-13 Information



For Reference Only

Part Number DXT13003DG-13

Manufacturer Diodes Incorporated

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single

Description TRANS NPN 450V 1.3A SOT223

Package TO-261-4, TO-261AA

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









DXT13003DG-13 Specifications

Manufacturer Part Number	DXT13003DG-13
Manufacturer	Diodes Incorporated
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-261-4, TO-261AA
Series	-
Transistor Type	NPN
Current - Collector (Ic) (Max)	1.3A
Voltage - Collector Emitter Breakdown (Max)	450V
Vce Saturation (Max) @ Ib, Ic	400mV @ 250mA, 1A
Current - Collector Cutoff (Max)	-
DC Current Gain (hFE) (Min) @ Ic, Vce	16 @ 500mA, 2V
Power - Max	700mW
Frequency - Transition	4MHz
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-261-4, TO-261AA
Supplier Device Package	SOT-223
	Report errors?

DXT13003DG-13 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

DXT13003DG-13 Payment Methods



















DXT13003DG-13 Shipping Methods













If you have any question about DXT13003DG-13, please do not hesitate to contact us!

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